CLAIMS

1. A ceramic heater with heat generation means disposed within a ceramic substrate, comprising:

at least part of said heat generation means being disposed on an offset level different from that of others of said heat generation means in the direction of thickness of said ceramic substrate.

2. The ceramic heater according to claim 1, wherein said heat generation means are disposed such that the level of adjoining ones to others is offset in the direction of thickness of said ceramic substrate.

3. The ceramic heater according to claims 1 or 2, wherein the form of said heat generation means is flat in cross-section.

4. The ceramic heater according to any one of claims 1 to 3, wherein the amount of offset displacement in level of said mutually adjacent heat generation means is in the range of 1 to 100 μm.

5. The ceramic heater according to any one of claims 1 to 4, wherein the maximum amount of offset displacement of said heat generation means is in the range of 3 to 500 μm.

6. The ceramic heater according to claims 1 or 2, wherein said heat generation means is constituted of a spiral wire body.

7. The ceramic heater according to any one of claims 1, 2 or 6, wherein the amount of offset displacement in level of said mutually adjacent heat generation means is in the range of 1 to 500 μm.

8. The ceramic heater according to any one of claims 1, 2, 6 or 7, wherein the maximum amount of offset displacement of said heat generation means is in the range of 5 to 2000 μm.

9. The ceramic heater according to any one of claims 1 to 8, wherein electrostatic electrodes are provided on said ceramic substrate.

10. The ceramic heater according to any one of claims 1 to 9, wherein a chuck-top conductor layer is formed on the surface of said ceramic substrate.